

## **BCP55-16-QX Datasheet**

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DiGi Electronics Part Number

Manufacturer Product Number

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Description

Manufacturer

**Detailed Description** 

BCP55-16-QX-DG

Nexperia USA Inc.

BCP55-16-QX

TRANS NPN 60V 1A SOT223

Bipolar (BJT) Transistor NPN 60 V 1 A 180MHz 650 m W Surface Mount SOT-223

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## Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BCP55-16-QX	Nexperia USA Inc.
Series:	Product Status:
BCP55-Q	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	1 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
60 V	500mV @ 50mA, 500mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	100 @ 150mA, 2V
Power - Max:	Frequency - Transition:
650 mW	180MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223
Base Product Number:	
BCP55	

## **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0075	



60 V, 1 A NPN medium power transistors Rev. 2 — 1 July 2022

**Product data sheet** 

## 1. General description

NPN medium power transistor series in a small SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

#### Table 1. Product overview

Type number	Package	Package		
	Nexperia	JEITA		
BCP55-Q	SOT223	SC73	BCP52-Q	
BCP55-10-Q			BCP52-10-Q	
BCP55-16-Q			BCP52-16-Q	

## 2. Features and benefits

- High current •
- Three current gain selections
- High power dissipation capability
- Qualified according to AEC-Q101 and recommended for use in automotive applications

### 3. Applications

- Linear voltage regulators
- Power management
- Low-side switches
- MOSFET drivers
- Battery-driven devices
- Amplifiers

## 4. Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	60	V
I <sub>C</sub>	collector current			-	-	1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-	2	А
h <sub>FE</sub>	DC current gain		·	·			
	BCP55-Q	$V_{CE}$ = 2 V; I <sub>C</sub> = 150 mA T <sub>amb</sub> = 25 °C	[1]	63	-	250	
	BCP55-10-Q		[1]	63	-	160	
	BCP55-16-Q		[1]	100	-	250	

[1] pulsed;  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ 

## nexperia

60 V, 1 A NPN medium power transistors

## 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	С
2	С	collector		
3	E	emitter		B-tx
4	С	collector	[]1 []2 []3	E
				sym123

## 6. Ordering information

Table 4. Ordering information						
Type number Package						
	Name	Description	Version			
BCP55-Q	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			
BCP55-10-Q						
BCP55-16-Q						

## 7. Marking

Table 5. Marking					
Type number	Marking code				
BCP55-Q	BCP55				
BCP55-10-Q	BCP55 /10				
BCP55-16-Q	BCP55 /16				

#### 60 V, 1 A NPN medium power transistors

## 8. Limiting values

#### Table 6. Limiting values

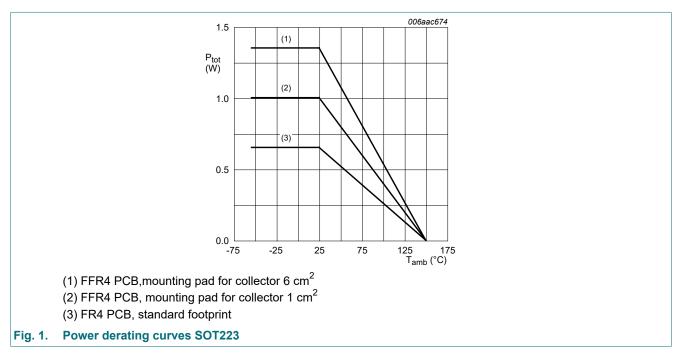
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	60	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
l <sub>C</sub>	collector current			-	1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	2	А
I <sub>B</sub>	base current			-	0.3	А
I <sub>BM</sub>	peak base current	single pulse; t <sub>p</sub> ≤ 1 ms		-	0.3	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	0.65	W
			[2]	-	1.00	W
			[3]	-	1.35	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1]

Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm<sup>2</sup><sub>2</sub>. [2]

Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 6 cm<sup>2</sup>. [3]



#### 60 V, 1 A NPN medium power transistors

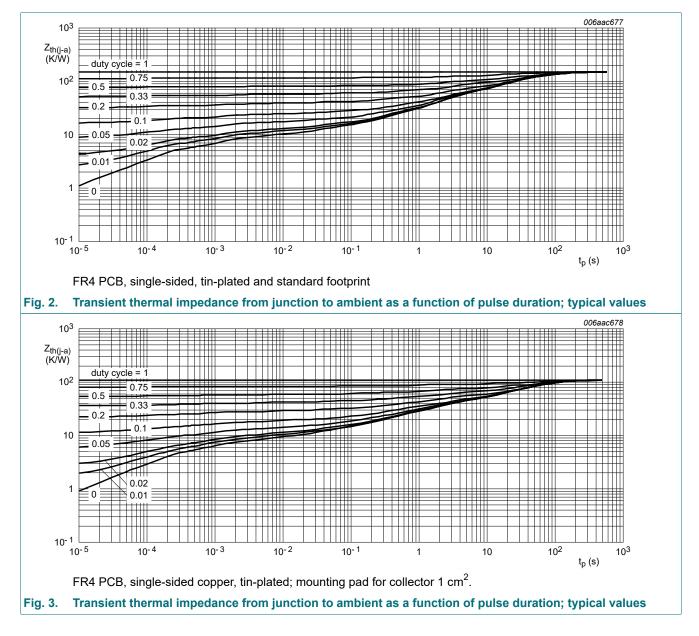
## 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	192	K/W	
			[2]	-	-	125	K/W	
			[3]	-	-	93	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	16	K/W	

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 1 cm<sup>2</sup>

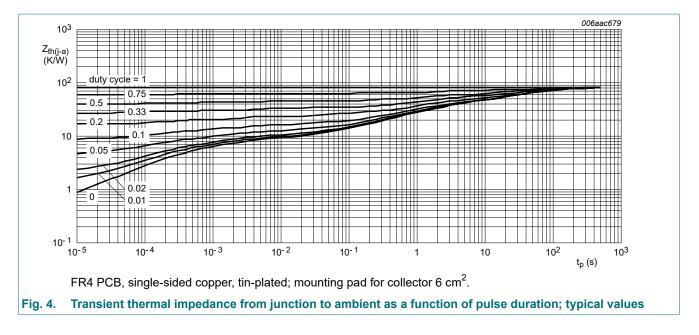
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated; monting pad for collector 6 cm<sup>2</sup>.



#### Nexperia

## **BCP55-Q series**

#### 60 V, 1 A NPN medium power transistors



BCP55-Q\_SER

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#### 60 V, 1 A NPN medium power transistors

## **10. Characteristics**

#### Table 8. Characteristics

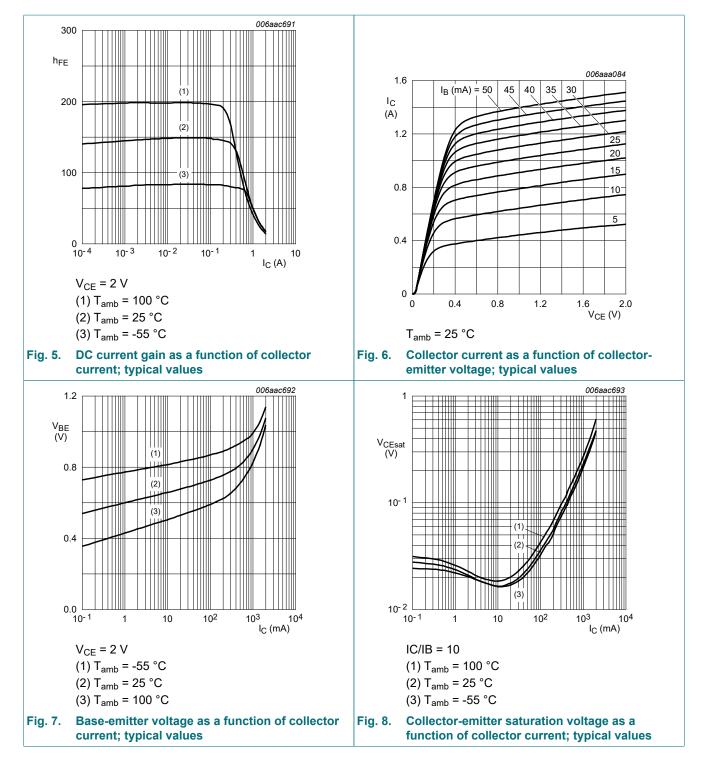
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	I <sub>C</sub> = 100 μA; I <sub>E</sub> = 0 ; T <sub>amb</sub> = 25 °C		60	-	-	V
V <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	I <sub>C</sub> = 2 μA; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		60	-	-	V
V <sub>(BR)EBO</sub>	emitter-base breakdown voltage	I <sub>C</sub> = 0 A; I <sub>E</sub> = 100 μA		5	-	-	V
I <sub>CBO</sub>	collector-base	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
	cut-off current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	10	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	100	nA
h <sub>FE</sub>	DC current gain						
	BCP55-Q	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	250	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
	BCP55-10-Q	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	160	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
	BCP55-16-Q	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 150 mA; T <sub>amb</sub> = 25 °C	[1]	100	-	250	
		V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 5 mA; T <sub>amb</sub> = 25 °C	[1]	63	-	-	
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	40	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 500 mA; I <sub>B</sub> = 50 mA; T <sub>amb</sub> = 25 °C	[1]	-	-	0.5	V
V <sub>BE</sub>	base-emitter voltage	V <sub>CE</sub> = 2 V; I <sub>C</sub> = 500 mA; T <sub>amb</sub> = 25 °C	[1]	-	-	1	V
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	6	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C		100	180	-	MHz

[1] pulsed;  $t_p \le 300 \ \mu s; \ \delta \le 0.02$ 

#### Nexperia

## **BCP55-Q** series

#### 60 V, 1 A NPN medium power transistors



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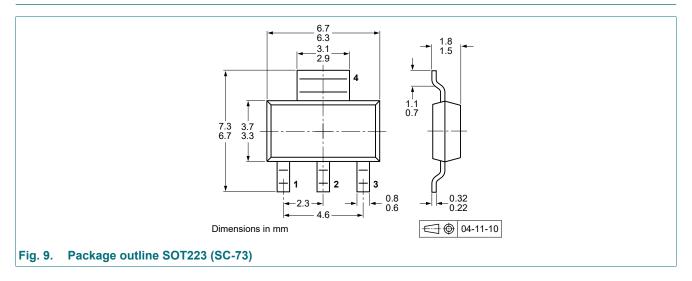
#### 60 V, 1 A NPN medium power transistors

## **11. Test information**

#### **11.1. Quality information**

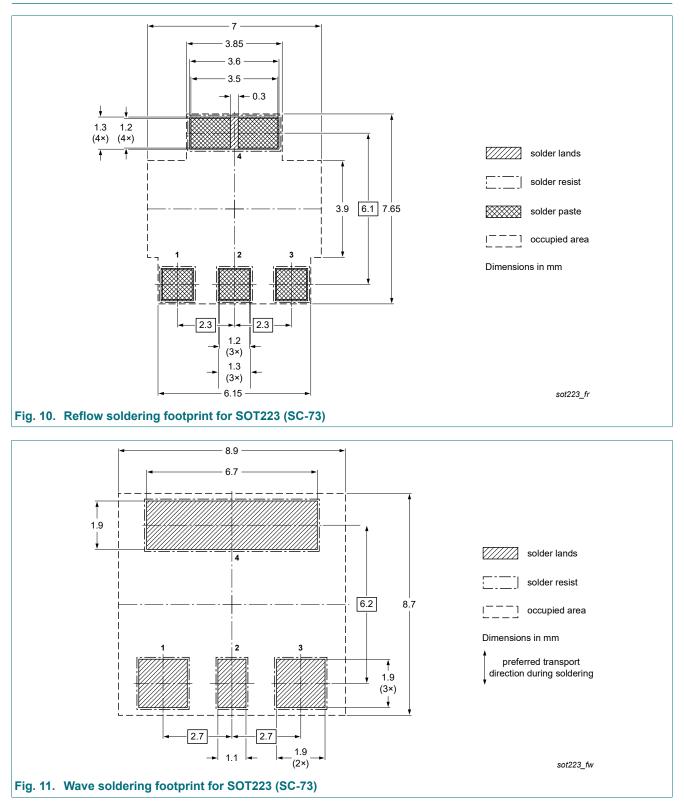
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

### 12. Package outline



#### 60 V, 1 A NPN medium power transistors

## 13. Soldering



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#### 60 V, 1 A NPN medium power transistors

## 14. Revision history

Table 9. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
BCP55-Q_SER v.2	20220701	Product data sheet	-	BCP55-Q_SER v.1			
Modifications:	Characteristics at V <sub>(BR)CEO</sub> : Conditions corrected						
BCP55-Q_SER v.1	20210623	Product data sheet	-	-			

BCP55-Q\_SER

#### 60 V, 1 A NPN medium power transistors

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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#### 60 V, 1 A NPN medium power transistors

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